

**isc Silicon NPN Power Transistor**
**BU208A**
**DESCRIPTION**

- High Voltage- $V_{CEX} = 1500V$ (Min.)
- Collector Current-  $I_C = 5.0A$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

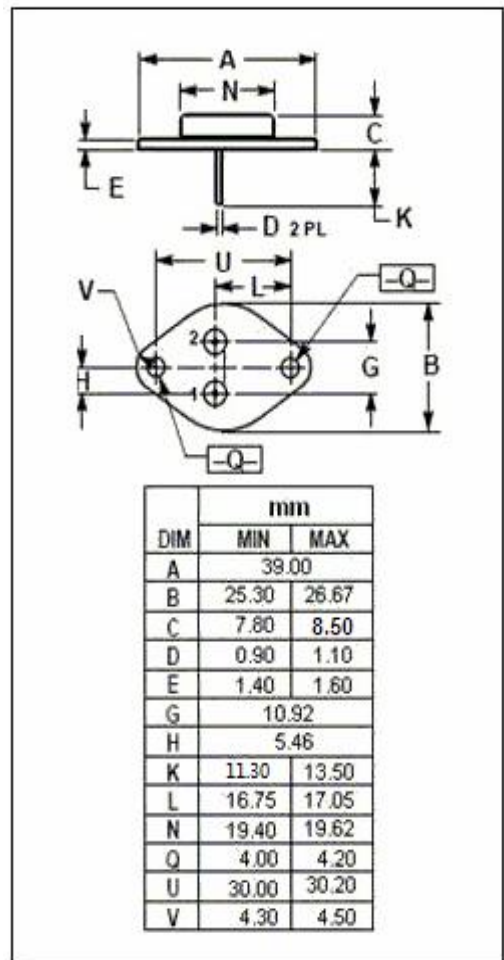
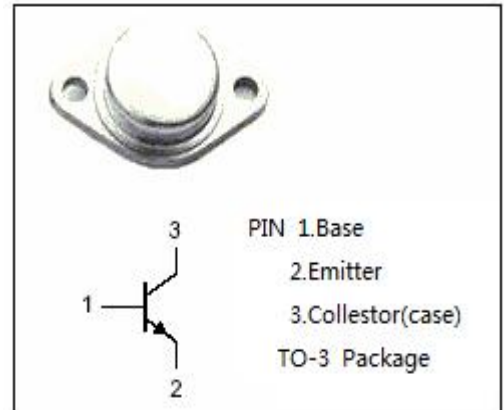
- Designed for use in large screen color deflection circuits .

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CEX}$	Collector-Emitter Voltage	1500	V
$V_{CEO}$	Collector-Emitter Voltage	700	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current-Continuous	8	A
$I_{CM}$	Collector Current-Peak	7.5	A
$I_B$	Base Current-Continuous	2.5	A
$P_C$	Collector Power Dissipation @ $T_c=25^\circ C$	150	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{stg}$	Storage Temperature	-65~150	$^\circ C$

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance,Junction to Case	1.64	$^\circ C/W$



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## BU208A

## ELECTRICAL CHARACTERISTICS

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	700			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4.5A; I <sub>B</sub> = 2A			1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4.5A; I <sub>B</sub> = 2A			1.5	V
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CE</sub> = 1500V; V <sub>BE</sub> = 0			1.0	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5.0V; I <sub>C</sub> = 0			10	mA
h <sub>FE 1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	8			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 4.5A; V <sub>CE</sub> = 5V	2.25			
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1MHz		125		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 5V; f <sub>test</sub> = 1MHz		4		MHz
t <sub>f</sub>	Fall Time	I <sub>C</sub> = 4.5A; I <sub>B</sub> = 1.8A; L <sub>B</sub> = 10 μ H		1.0		μ s

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